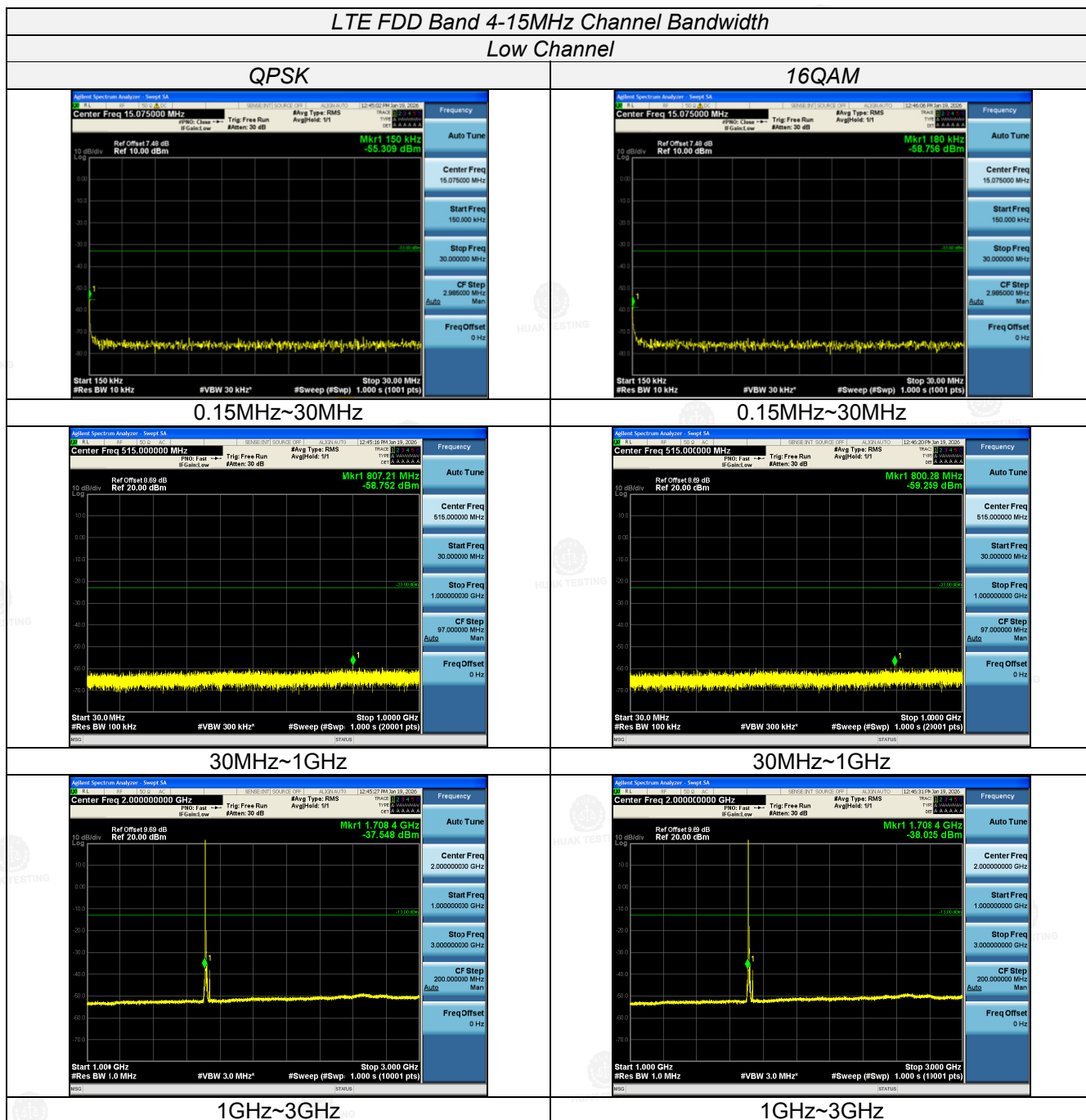
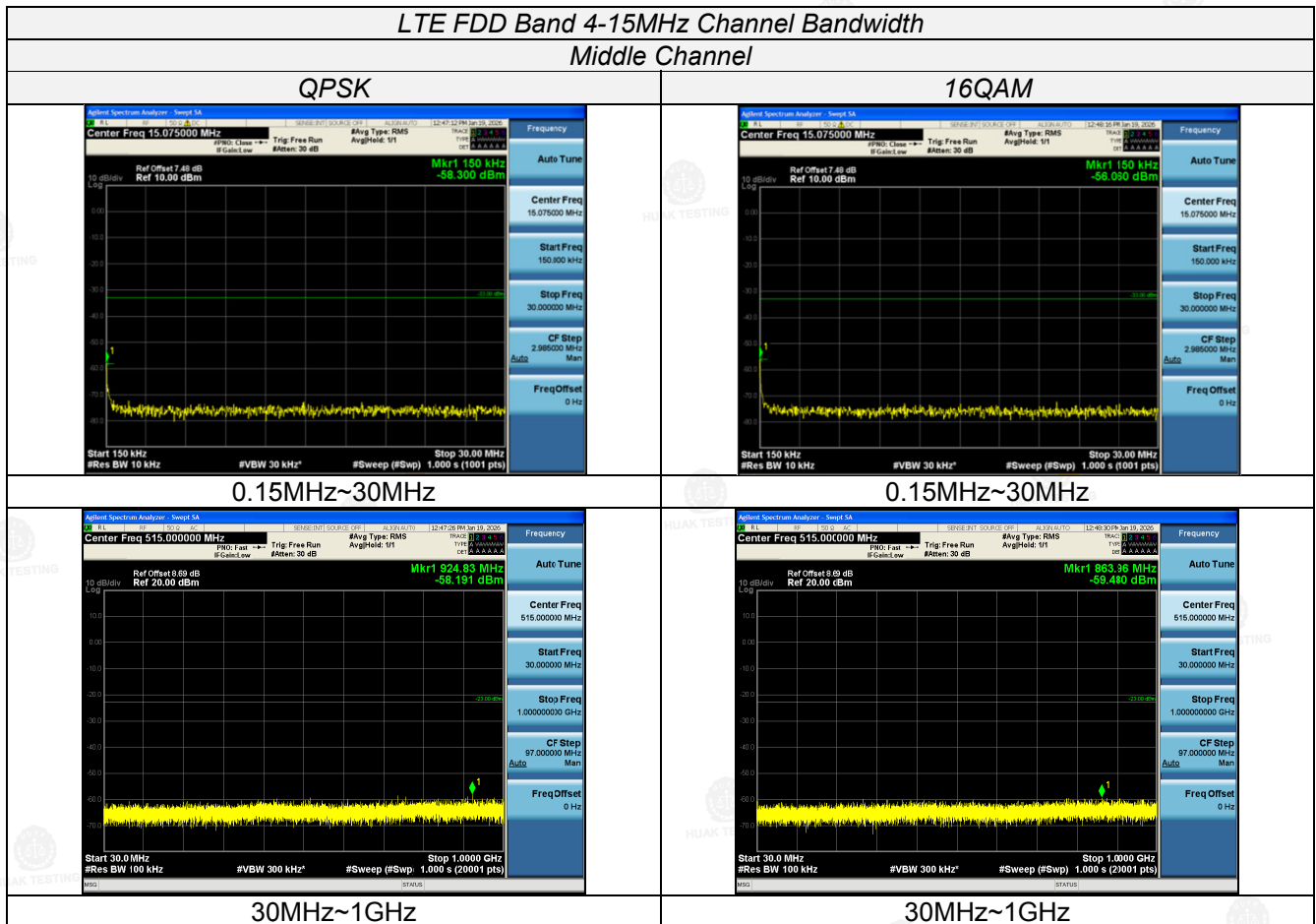
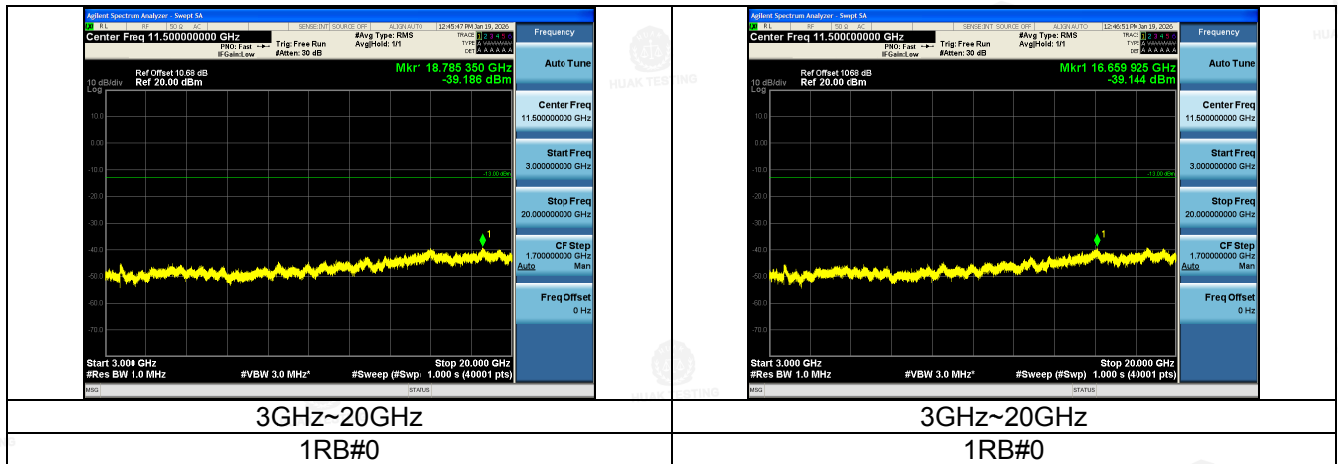
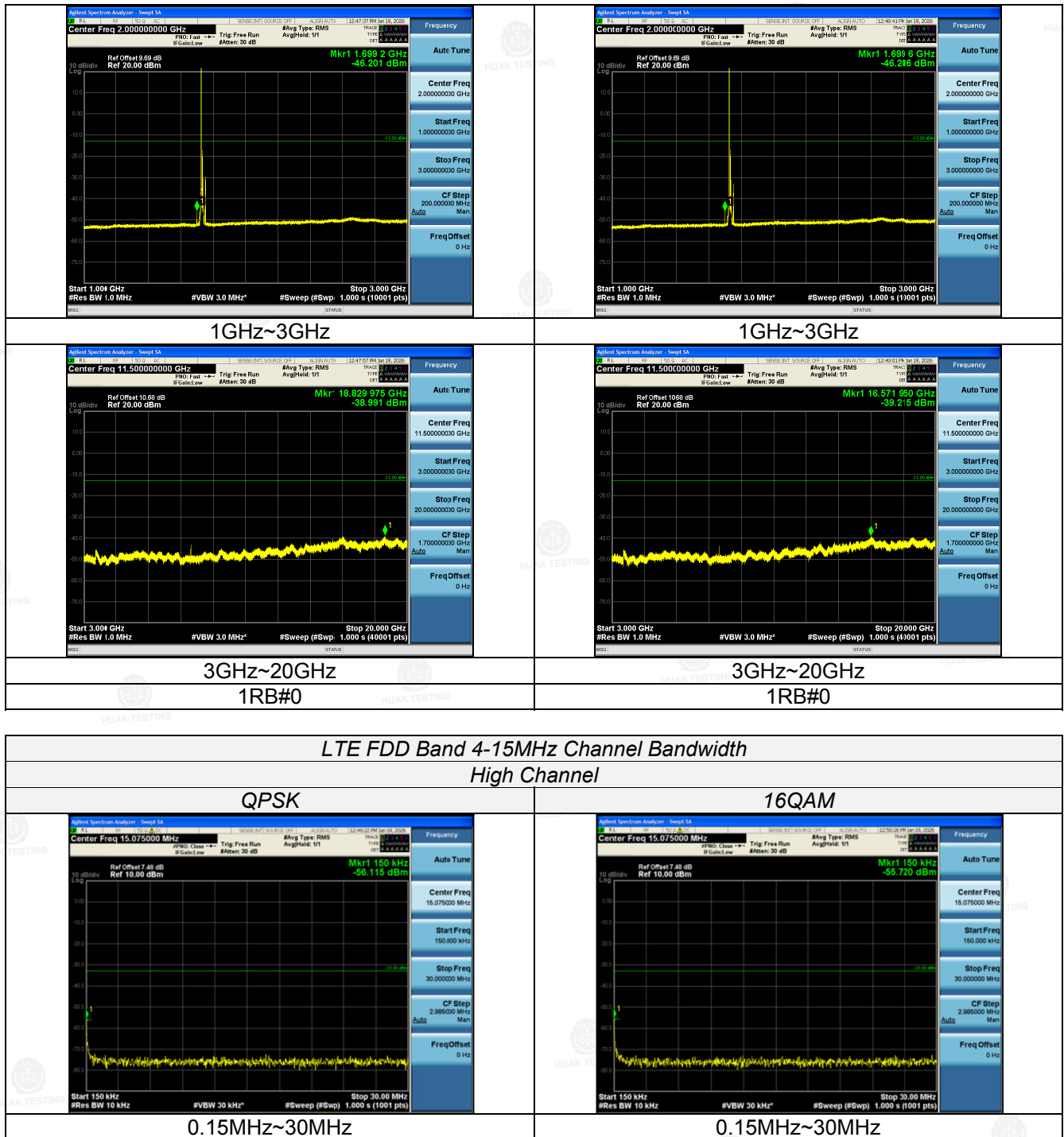
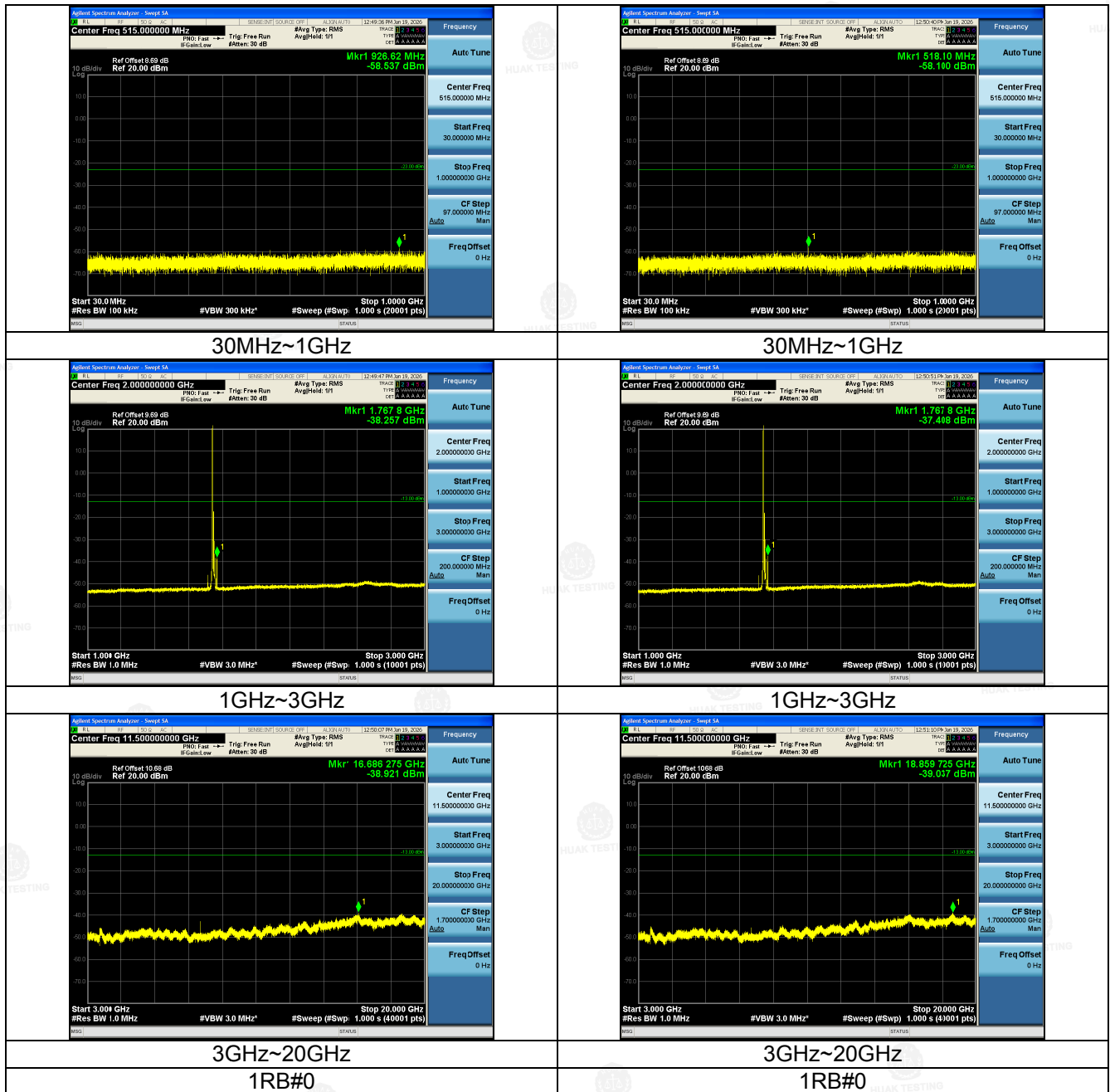
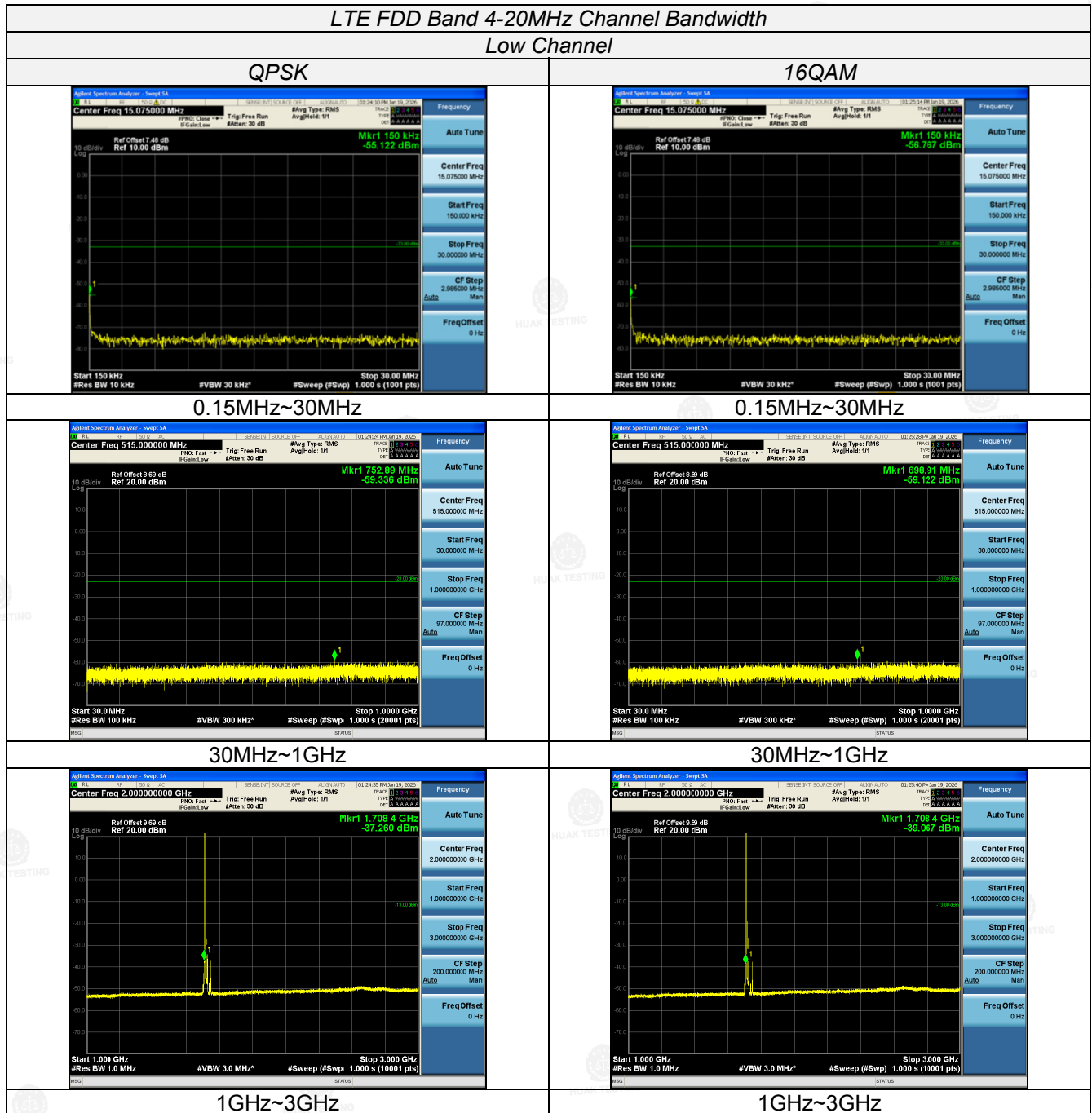




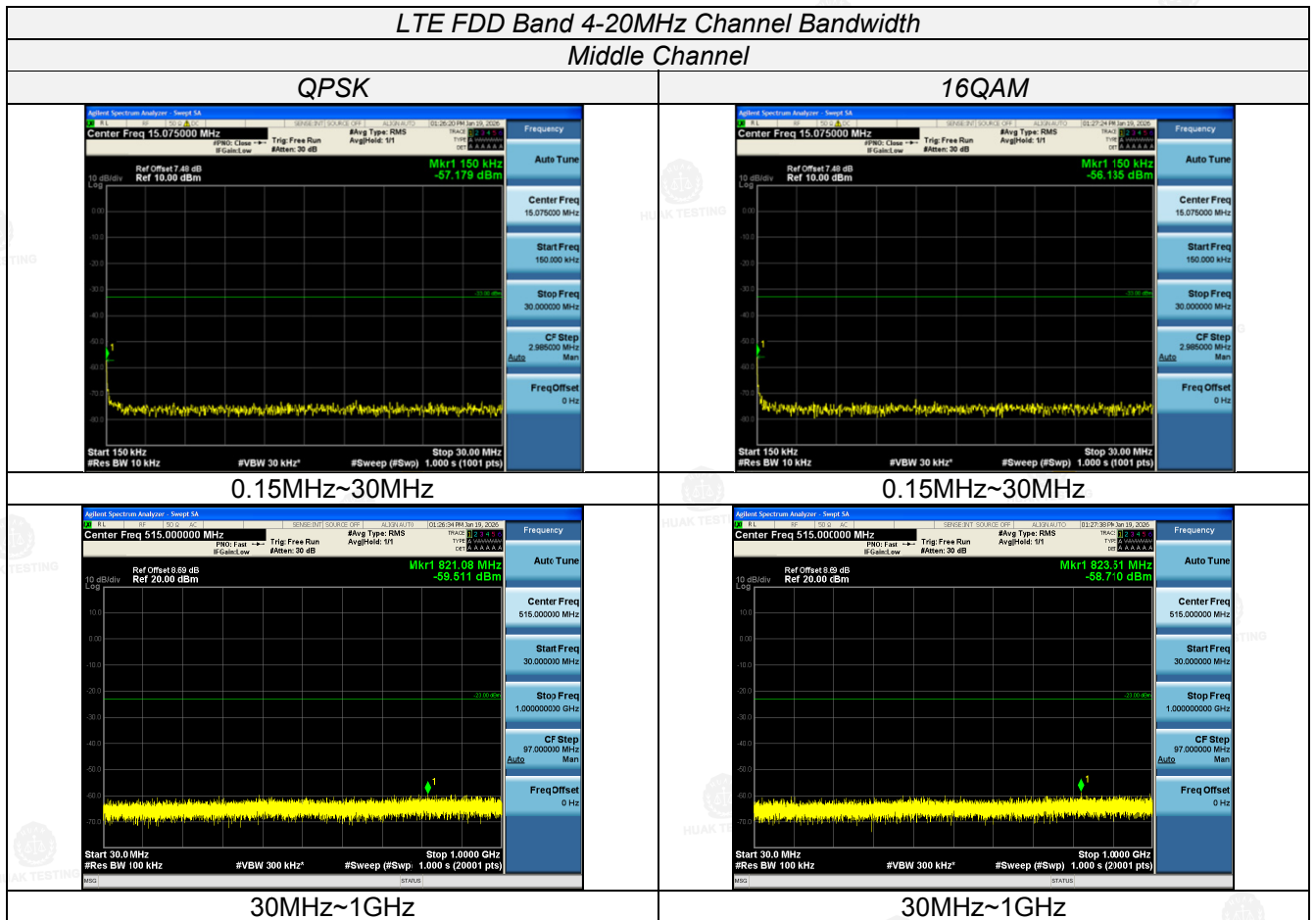
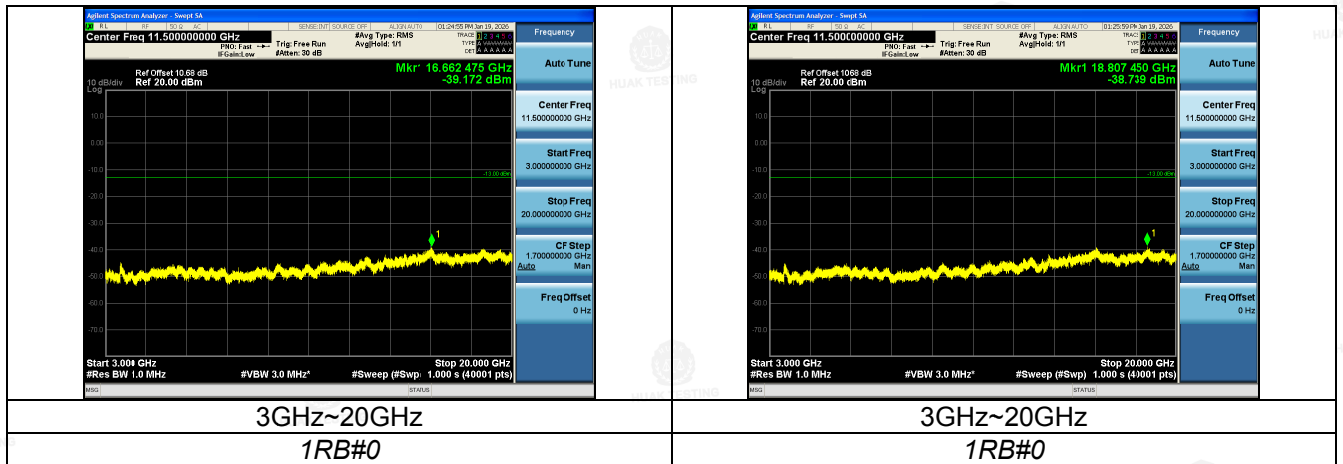


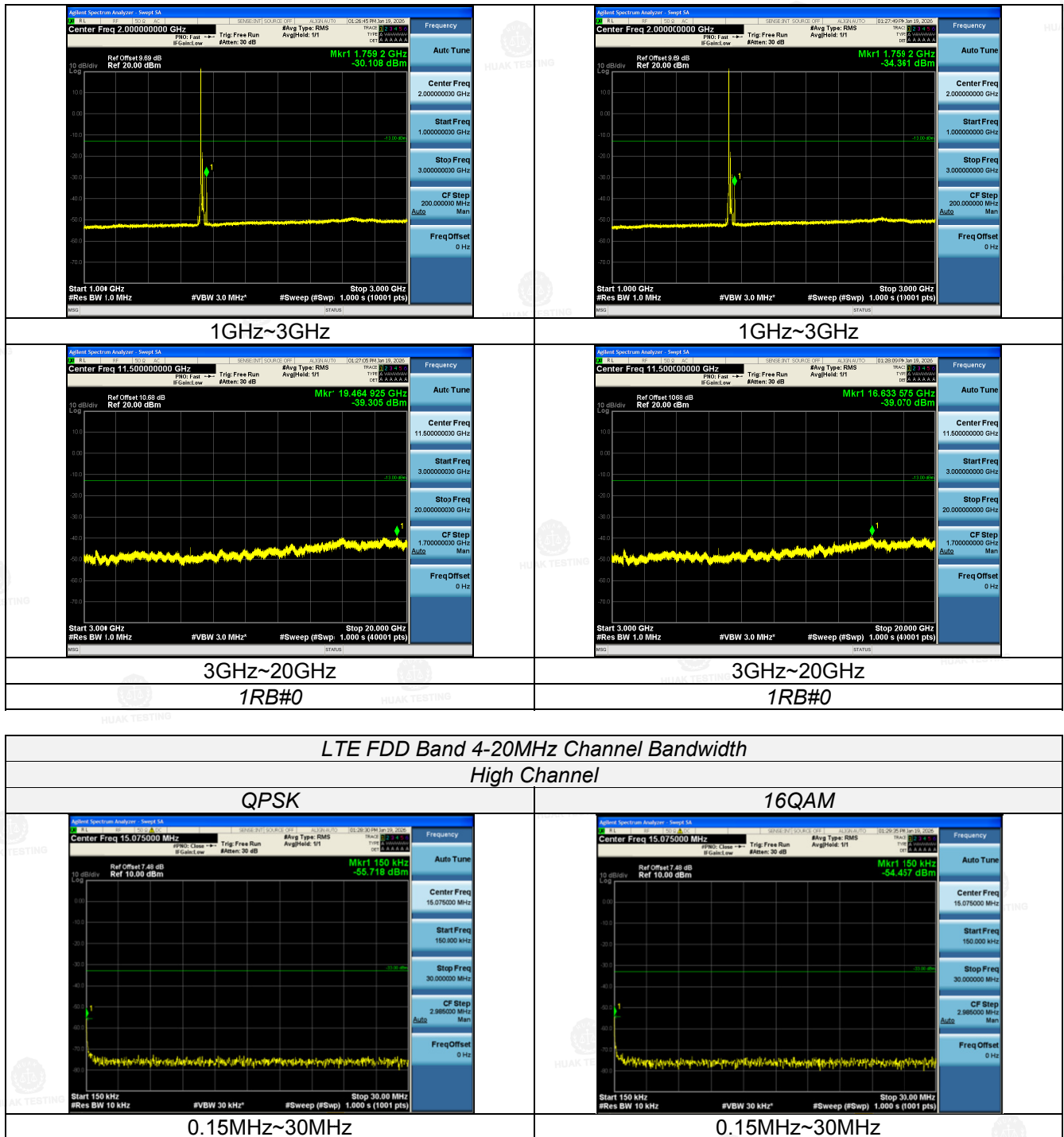


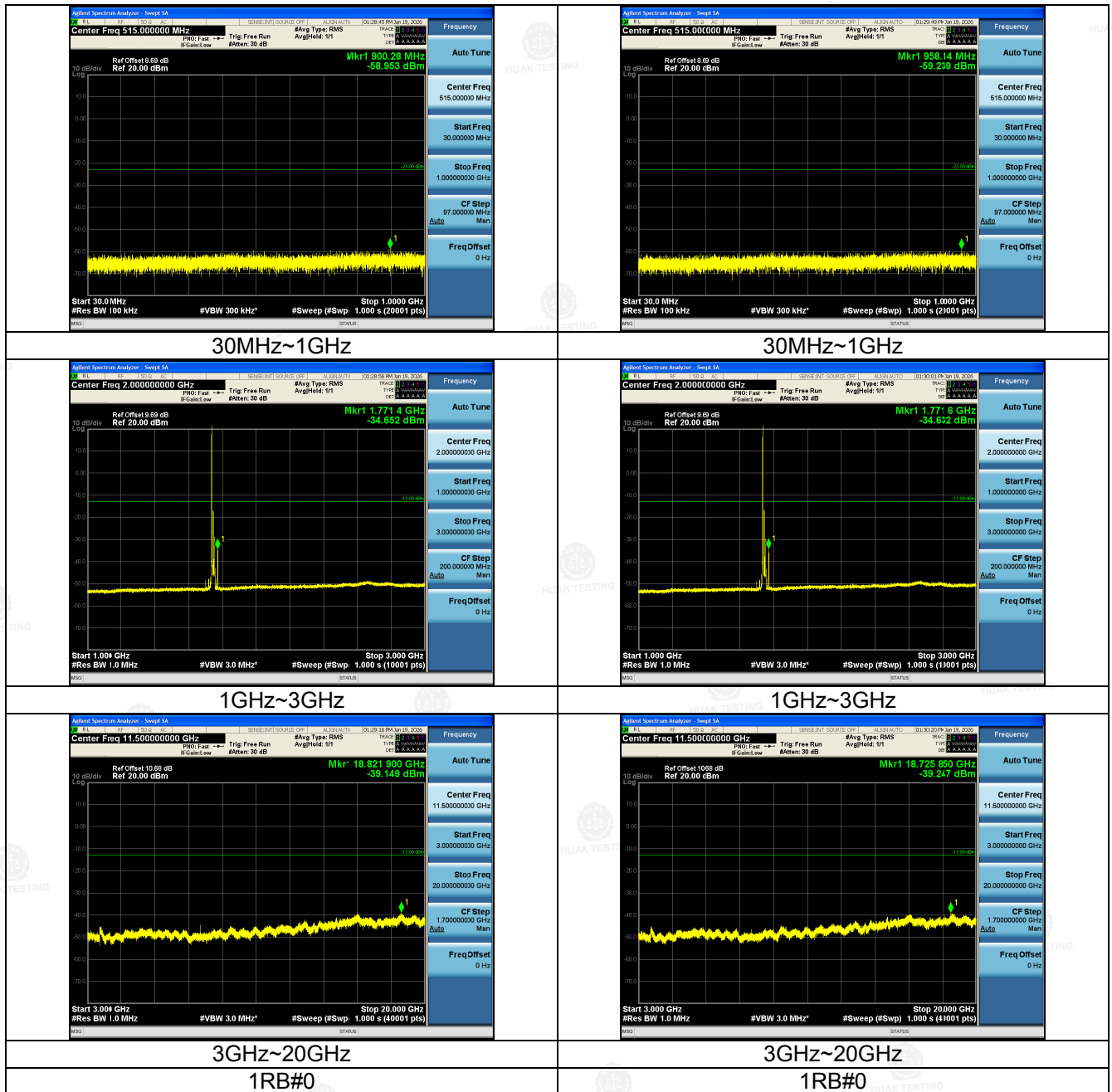




The results shown in this test report refer only to the sample(s) tested unless otherwise stated and the sample(s) are retained for 15 days only. The document is issued by Shenzhen HUAKE Testing Technology Co., Ltd., this document cannot be reproduced except in full with our prior written permission.







Radiated Measurement:

Remark:

1. We were tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 4; recorded worst case for each Channel Bandwidth of LTE FDD Band 4.
2. $EIRP = P_{Mea}(dBm) - P_{cl}(dB) + G_a(dBi)$
3. We were not recorded other points as values lower than limits.
4. $Margin = Limit - EIRP$

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3421.4	-47.12	4.02	3.00	12.50	-38.64	-13.00	25.64	H
5132.1	-52.20	5.11	3.00	13.38	-43.93	-13.00	30.93	H
3421.4	-54.54	4.02	3.00	12.50	-46.06	-13.00	33.06	V
5132.1	-54.09	5.11	3.00	13.38	-45.82	-13.00	32.82	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.46	4.02	3.00	12.45	-36.03	-13.00	23.03	H
5197.5	-49.08	5.11	3.00	13.38	-40.81	-13.00	27.81	H
3465.0	-54.92	4.02	3.00	12.45	-46.49	-13.00	33.49	V
5197.5	-51.19	5.11	3.00	13.38	-42.92	-13.00	29.92	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3508.6	-44.89	4.02	3.00	12.21	-36.70	-13.00	23.70	H
5262.9	-49.98	5.11	3.00	13.26	-41.83	-13.00	28.83	H
3508.6	-53.72	4.02	3.00	12.21	-45.53	-13.00	32.53	V
5262.9	-50.89	5.11	3.00	13.26	-42.74	-13.00	29.74	V

LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3423.0	-46.74	4.02	3.00	12.50	-38.26	-13.00	25.26	H
5134.5	-51.54	5.11	3.00	13.38	-43.27	-13.00	30.27	H
3423.0	-55.06	4.02	3.00	12.50	-46.58	-13.00	33.58	V
5134.5	-54.19	5.11	3.00	13.38	-45.92	-13.00	32.92	V

LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.50	4.02	3.00	12.45	-36.07	-13.00	23.07	H
5197.5	-49.83	5.11	3.00	13.38	-41.56	-13.00	28.56	H
3465.0	-54.62	4.02	3.00	12.45	-46.19	-13.00	33.19	V
5197.5	-51.85	5.11	3.00	13.38	-43.58	-13.00	30.58	V



LTE FDD Band 4_Channel Bandwidth 3MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3507.0	-44.07	4.02	3.00	12.21	-35.88	-13.00	22.88	H
5260.5	-49.47	5.11	3.00	13.26	-41.32	-13.00	28.32	H
3507.0	-53.63	4.02	3.00	12.21	-45.44	-13.00	32.44	V
5260.5	-51.07	5.11	3.00	13.26	-42.92	-13.00	29.92	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3425.0	-46.68	4.02	3.00	12.50	-38.20	-13.00	25.20	H
5137.5	-52.24	5.11	3.00	13.38	-43.97	-13.00	30.97	H
3425.0	-55.05	4.02	3.00	12.50	-46.57	-13.00	33.57	V
5137.5	-54.07	5.11	3.00	13.38	-45.80	-13.00	32.80	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-43.71	4.02	3.00	12.45	-35.28	-13.00	22.28	H
5197.5	-49.82	5.11	3.00	13.38	-41.55	-13.00	28.55	H
3465.0	-55.17	4.02	3.00	12.45	-46.74	-13.00	33.74	V
5197.5	-51.09	5.11	3.00	13.38	-42.82	-13.00	29.82	V

LTE FDD Band 4_Channel Bandwidth 5MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3505.0	-44.76	4.02	3.00	12.21	-36.57	-13.00	23.57	H
5257.5	-49.90	5.11	3.00	13.26	-41.75	-13.00	28.75	H
3505.0	-53.19	4.02	3.00	12.21	-45.00	-13.00	32.00	V
5257.5	-50.81	5.11	3.00	13.26	-42.66	-13.00	29.66	V

LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3430.0	-46.65	4.02	3.00	12.50	-38.17	-13.00	25.17	H
5145.0	-52.11	5.11	3.00	13.38	-43.84	-13.00	30.84	H
3430.0	-54.61	4.02	3.00	12.50	-46.13	-13.00	33.13	V
5145.0	-54.00	5.11	3.00	13.38	-45.73	-13.00	32.73	V

LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.48	4.02	3.00	12.45	-36.05	-13.00	23.05	H
5197.5	-49.35	5.11	3.00	13.38	-41.08	-13.00	28.08	H
3465.0	-54.68	4.02	3.00	12.45	-46.25	-13.00	33.25	V
5197.5	-51.18	5.11	3.00	13.38	-42.91	-13.00	29.91	V



LTE FDD Band 4_Channel Bandwidth 10MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3500.0	-44.60	4.02	3.00	12.21	-36.41	-13.00	23.41	H
5250.0	-49.46	5.11	3.00	13.26	-41.31	-13.00	28.31	H
3500.0	-53.74	4.02	3.00	12.21	-45.55	-13.00	32.55	V
5250.0	-50.71	5.11	3.00	13.26	-42.56	-13.00	29.56	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3435.0	-46.75	4.02	3.00	12.50	-38.27	-13.00	25.27	H
5152.5	-51.34	5.11	3.00	13.38	-43.07	-13.00	30.07	H
3435.0	-54.31	4.02	3.00	12.50	-45.83	-13.00	32.83	V
5152.5	-54.13	5.11	3.00	13.38	-45.86	-13.00	32.86	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-43.91	4.02	3.00	12.45	-35.48	-13.00	22.48	H
5197.5	-49.71	5.11	3.00	13.38	-41.44	-13.00	28.44	H
3465.0	-54.24	4.02	3.00	12.45	-45.81	-13.00	32.81	V
5197.5	-51.90	5.11	3.00	13.38	-43.63	-13.00	30.63	V

LTE FDD Band 4_Channel Bandwidth 15MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3495.0	-44.09	4.02	3.00	12.21	-35.90	-13.00	22.90	H
5242.5	-49.23	5.11	3.00	13.26	-41.08	-13.00	28.08	H
3495.0	-53.74	4.02	3.00	12.21	-45.55	-13.00	32.55	V
5242.5	-50.19	5.11	3.00	13.26	-42.04	-13.00	29.04	V

LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3440.0	-46.76	4.02	3.00	12.50	-38.28	-13.00	25.28	H
5160.0	-51.36	5.11	3.00	13.38	-43.09	-13.00	30.09	H
3440.0	-55.01	4.02	3.00	12.50	-46.53	-13.00	33.53	V
5160.0	-53.85	5.11	3.00	13.38	-45.58	-13.00	32.58	V

LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.03	4.02	3.00	12.45	-35.60	-13.00	22.60	H
5197.5	-50.03	5.11	3.00	13.38	-41.76	-13.00	28.76	H
3465.0	-54.63	4.02	3.00	12.45	-46.20	-13.00	33.20	V
5197.5	-51.59	5.11	3.00	13.38	-43.32	-13.00	30.32	V



LTE FDD Band 4_Channel Bandwidth 20MHz_QPSK_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490.0	-44.27	4.02	3.00	12.21	-36.08	-13.00	23.08	H
5235.0	-50.05	5.11	3.00	13.26	-41.90	-13.00	28.90	H
3490.0	-53.08	4.02	3.00	12.21	-44.89	-13.00	31.89	V
5235.0	-51.03	5.11	3.00	13.26	-42.88	-13.00	29.88	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3421.4	-46.90	4.02	3.00	12.50	-38.42	-13.00	25.42	H
5132.1	-51.61	5.11	3.00	13.38	-43.34	-13.00	30.34	H
3421.4	-54.67	4.02	3.00	12.50	-46.19	-13.00	33.19	V
5132.1	-53.92	5.11	3.00	13.38	-45.65	-13.00	32.65	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.51	4.02	3.00	12.45	-36.08	-13.00	23.08	H
5197.5	-49.47	5.11	3.00	13.38	-41.20	-13.00	28.20	H
3465.0	-54.58	4.02	3.00	12.45	-46.15	-13.00	33.15	V
5197.5	-51.31	5.11	3.00	13.38	-43.04	-13.00	30.04	V

LTE FDD Band 4_Channel Bandwidth 1.4MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3508.6	-44.63	4.02	3.00	12.21	-36.44	-13.00	23.44	H
5262.9	-49.37	5.11	3.00	13.26	-41.22	-13.00	28.22	H
3508.6	-53.02	4.02	3.00	12.21	-44.83	-13.00	31.83	V
5262.9	-50.86	5.11	3.00	13.26	-42.71	-13.00	29.71	V

LTE FDD Band 4_Channel Bandwidth 3MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3423.0	-47.07	4.02	3.00	12.50	-38.59	-13.00	25.59	H
5134.5	-51.96	5.11	3.00	13.38	-43.69	-13.00	30.69	H
3423.0	-54.96	4.02	3.00	12.50	-46.48	-13.00	33.48	V
5134.5	-54.72	5.11	3.00	13.38	-46.45	-13.00	33.45	V

LTE FDD Band 4_Channel Bandwidth 3MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.47	4.02	3.00	12.45	-36.04	-13.00	23.04	H
5197.5	-49.94	5.11	3.00	13.38	-41.67	-13.00	28.67	H
3465.0	-54.99	4.02	3.00	12.45	-46.56	-13.00	33.56	V
5197.5	-51.98	5.11	3.00	13.38	-43.71	-13.00	30.71	V



LTE FDD Band 4_Channel Bandwidth 3MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3507.0	-44.13	4.02	3.00	12.21	-35.94	-13.00	22.94	H
5260.5	-49.60	5.11	3.00	13.26	-41.45	-13.00	28.45	H
3507.0	-53.27	4.02	3.00	12.21	-45.08	-13.00	32.08	V
5260.5	-50.11	5.11	3.00	13.26	-41.96	-13.00	28.96	V

LTE FDD Band 4_Channel Bandwidth 5MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3425.0	-47.31	4.02	3.00	12.50	-38.83	-13.00	25.83	H
5137.5	-51.51	5.11	3.00	13.38	-43.24	-13.00	30.24	H
3425.0	-54.50	4.02	3.00	12.50	-46.02	-13.00	33.02	V
5137.5	-54.29	5.11	3.00	13.38	-46.02	-13.00	33.02	V

LTE FDD Band 4_Channel Bandwidth 5MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.28	4.02	3.00	12.45	-35.85	-13.00	22.85	H
5197.5	-49.62	5.11	3.00	13.38	-41.35	-13.00	28.35	H
3465.0	-54.52	4.02	3.00	12.45	-46.09	-13.00	33.09	V
5197.5	-51.37	5.11	3.00	13.38	-43.10	-13.00	30.10	V

LTE FDD Band 4_Channel Bandwidth 5MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3505.0	-44.73	4.02	3.00	12.21	-36.54	-13.00	23.54	H
5257.5	-49.26	5.11	3.00	13.26	-41.11	-13.00	28.11	H
3505.0	-53.63	4.02	3.00	12.21	-45.44	-13.00	32.44	V
5257.5	-51.01	5.11	3.00	13.26	-42.86	-13.00	29.86	V

LTE FDD Band 4_Channel Bandwidth 10MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3430.0	-47.16	4.02	3.00	12.50	-38.68	-13.00	25.68	H
5145.0	-52.01	5.11	3.00	13.38	-43.74	-13.00	30.74	H
3430.0	-54.79	4.02	3.00	12.50	-46.31	-13.00	33.31	V
5145.0	-54.64	5.11	3.00	13.38	-46.37	-13.00	33.37	V

LTE FDD Band 4_Channel Bandwidth 10MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-44.21	4.02	3.00	12.45	-35.78	-13.00	22.78	H
5197.5	-49.60	5.11	3.00	13.38	-41.33	-13.00	28.33	H
3465.0	-54.62	4.02	3.00	12.45	-46.19	-13.00	33.19	V
5197.5	-51.72	5.11	3.00	13.38	-43.45	-13.00	30.45	V



LTE FDD Band 4_Channel Bandwidth 10MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3500.0	-44.24	4.02	3.00	12.21	-36.05	-13.00	23.05	H
5250.0	-49.93	5.11	3.00	13.26	-41.78	-13.00	28.78	H
3500.0	-53.11	4.02	3.00	12.21	-44.92	-13.00	31.92	V
5250.0	-51.01	5.11	3.00	13.26	-42.86	-13.00	29.86	V

LTE FDD Band 4_Channel Bandwidth 15MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3435.0	-47.34	4.02	3.00	12.50	-38.86	-13.00	25.86	H
5152.5	-52.27	5.11	3.00	13.38	-44.00	-13.00	31.00	H
3435.0	-54.22	4.02	3.00	12.50	-45.74	-13.00	32.74	V
5152.5	-54.73	5.11	3.00	13.38	-46.46	-13.00	33.46	V

LTE FDD Band 4_Channel Bandwidth 15MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-43.78	4.02	3.00	12.45	-35.35	-13.00	22.35	H
5197.5	-49.17	5.11	3.00	13.38	-40.90	-13.00	27.90	H
3465.0	-54.51	4.02	3.00	12.45	-46.08	-13.00	33.08	V
5197.5	-51.26	5.11	3.00	13.38	-42.99	-13.00	29.99	V

LTE FDD Band 4_Channel Bandwidth 15MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3495.0	-44.07	4.02	3.00	12.21	-35.88	-13.00	22.88	H
5242.5	-49.27	5.11	3.00	13.26	-41.12	-13.00	28.12	H
3495.0	-52.95	4.02	3.00	12.21	-44.76	-13.00	31.76	V
5242.5	-50.18	5.11	3.00	13.26	-42.03	-13.00	29.03	V

LTE FDD Band 4_Channel Bandwidth 20MHz_16QAM_Low Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	Peak EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3440.0	-46.64	4.02	3.00	12.50	-38.16	-13.00	25.16	H
5160.0	-52.23	5.11	3.00	13.38	-43.96	-13.00	30.96	H
3440.0	-54.13	4.02	3.00	12.50	-45.65	-13.00	32.65	V
5160.0	-53.81	5.11	3.00	13.38	-45.54	-13.00	32.54	V

LTE FDD Band 4_Channel Bandwidth 20MHz_16QAM_Middle Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3465.0	-43.90	4.02	3.00	12.45	-35.47	-13.00	22.47	H
5197.5	-49.87	5.11	3.00	13.38	-41.60	-13.00	28.60	H
3465.0	-54.43	4.02	3.00	12.45	-46.00	-13.00	33.00	V
5197.5	-51.83	5.11	3.00	13.38	-43.56	-13.00	30.56	V



LTE FDD Band 4_Channel Bandwidth 20MHz_16QAM_High Channel

Frequency (MHz)	PMea (dBm)	Pcl (dB)	Diatance	Ga Antenna Gain(dB)	EIRP (dBm)	Limit (dBm)	Margin (dB)	Polarization
3490.0	-44.00	4.02	3.00	12.21	-35.81	-13.00	22.81	H
5235.0	-49.97	5.11	3.00	13.26	-41.82	-13.00	28.82	H
3490.0	-53.74	4.02	3.00	12.21	-45.55	-13.00	32.55	V
5235.0	-50.80	5.11	3.00	13.26	-42.65	-13.00	29.65	V

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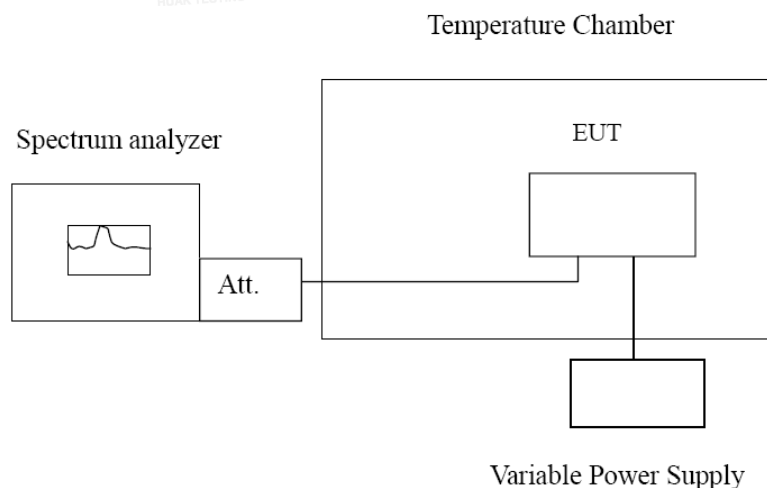


3.6 Frequency Stability Under Temperature & Voltage Variations

LIMIT

According to §27.54, §2.1055 requirement, the frequency stability shall be sufficient to ensure that the fundamental emissions stay within the authorized bands of operation and should not exceed 2.5ppm.

TEST CONFIGURATION



TEST PROCEDURE

The EUT was setup according to ANSI/TIA-603-E.

Frequency Stability Under Temperature Variations:

In order to measure the carrier frequency under the condition of AFC lock, it is necessary to make measurements with the EUT in a "call mode". This is accomplished with the use of R&S CMW500 DIGITAL RADIO COMMUNICATION TESTER.

1. Measure the carrier frequency at room temperature.
2. Subject the EUT to overnight soak at -30°C.
3. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on middle channel for LTE band 4, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
4. Repeat the above measurements at 10°C increments from -30°C to +50°C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
5. Re-measure carrier frequency at room temperature with nominal voltage. Vary supply voltage from minimum voltage to maximum voltage, in 0.1Volt increments re-measuring carrier frequency at each voltage. Pause at nominal voltage for 1.5 hours unpowered, to allow any self-heating to stabilize, before continuing.
6. Subject the EUT to overnight soak at +50°C.
7. With the EUT, powered via nominal voltage, connected to the CMW500 and in a simulated call on the centre channel, measure the carrier frequency. These measurements should be made within 2 minutes of Powering up the EUT, to prevent significant self-warming.
8. Repeat the above measurements at 10 °C increments from +50°C to -30°C. Allow at least 1.5 hours at each temperature, unpowered, before making measurements.
9. At all temperature levels hold the temperature to +/- 0.5°C during the measurement procedure.

Frequency Stability Under Voltage Variations:

Set chamber temperature to 20°C. Use a variable AC power supply / DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency.

Reduce the input voltage to specify extreme voltage variation ($\pm 15\%$) and endpoint, record the maximum frequency change.

**Remark:**

1. We tested all RB Configuration refer 3GPP TS136 521 for each Channel Bandwidth of LTE FDD Band 4; recorded worst case.

LTE Band 4, 1.4MHz bandwidth, QPSK (worst case of all bandwidths).

LTE FDD Band 4				
DC Power(V)	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Verdict
10.20	20	7.87	0.004600	PASS
12.00	20	6.07	0.003548	PASS
13.80	20	3.75	0.002192	PASS
12.00	-30	6.47	0.003782	PASS
12.00	-20	6.81	0.003981	PASS
12.00	-10	4.81	0.002812	PASS
12.00	0	5.02	0.002934	PASS
12.00	10	6.61	0.003864	PASS
12.00	20	5.21	0.003046	PASS
12.00	30	4.22	0.002467	PASS
12.00	40	4.01	0.002344	PASS
12.00	50	10.27	0.006003	PASS

LTE Band 4, 1.4MHz bandwidth, 16QAM (worst case of all bandwidths)

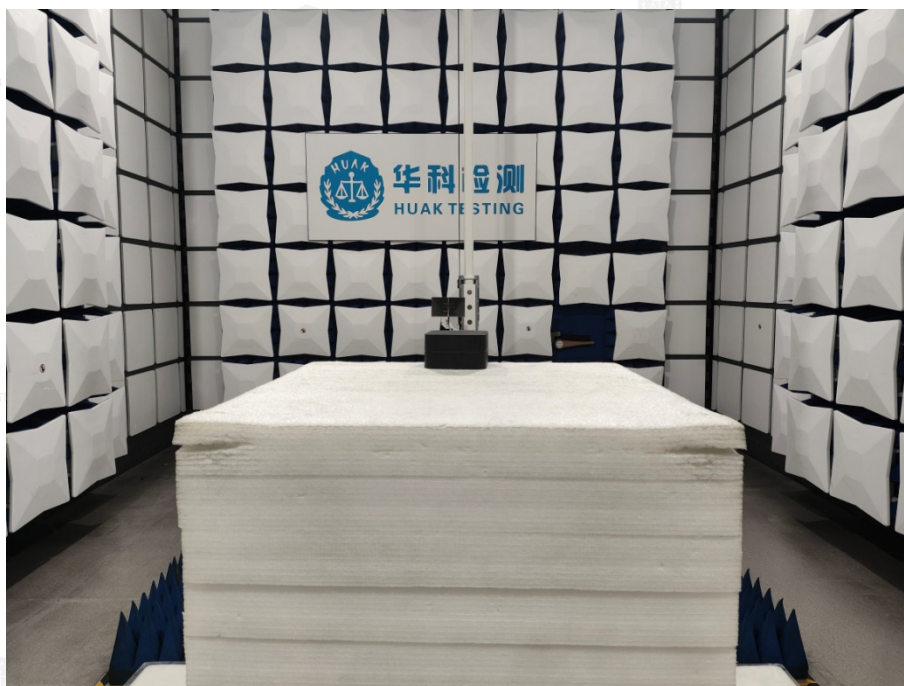
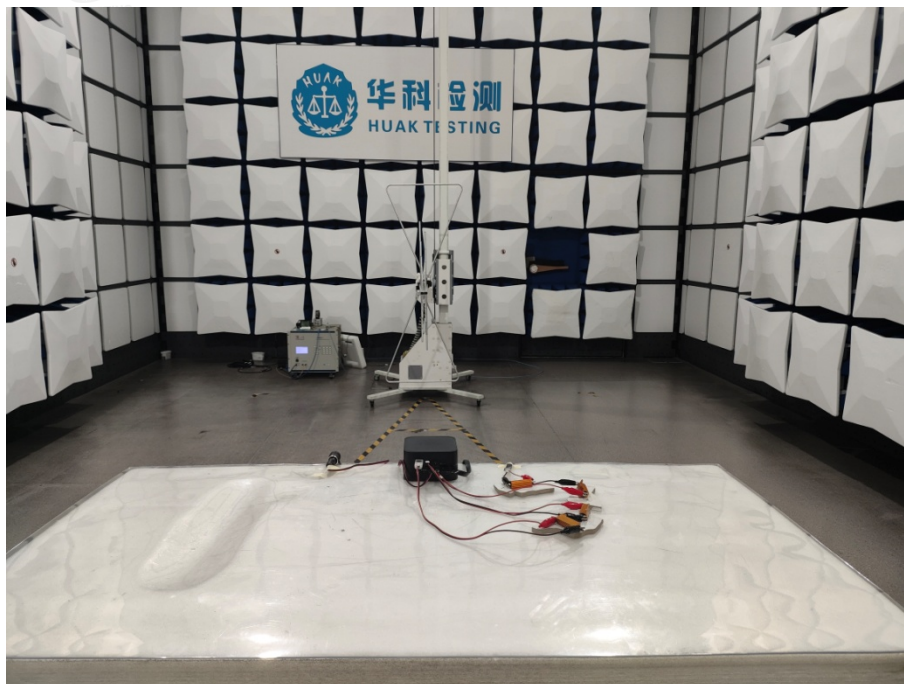
LTE FDD Band 4				
DC Power(V)	Temperature (°C)	Frequency error(Hz)	Frequency error(ppm)	Verdict
10.20	20	4.53	0.002615	PASS
12.00	20	-4.81	-0.002776	PASS
13.80	20	2.83	0.001633	PASS
12.00	-30	7.31	0.004219	PASS
12.00	-20	4.82	0.002782	PASS
12.00	-10	-3.76	-0.002170	PASS
12.00	0	-4.12	-0.002378	PASS
12.00	10	3.40	0.001962	PASS
12.00	20	-4.03	-0.002326	PASS
12.00	30	-5.46	-0.003152	PASS
12.00	40	4.51	0.002603	PASS
12.00	50	5.72	0.003302	PASS



HUAKE TESTING

4 Test Setup Photos of the EUT

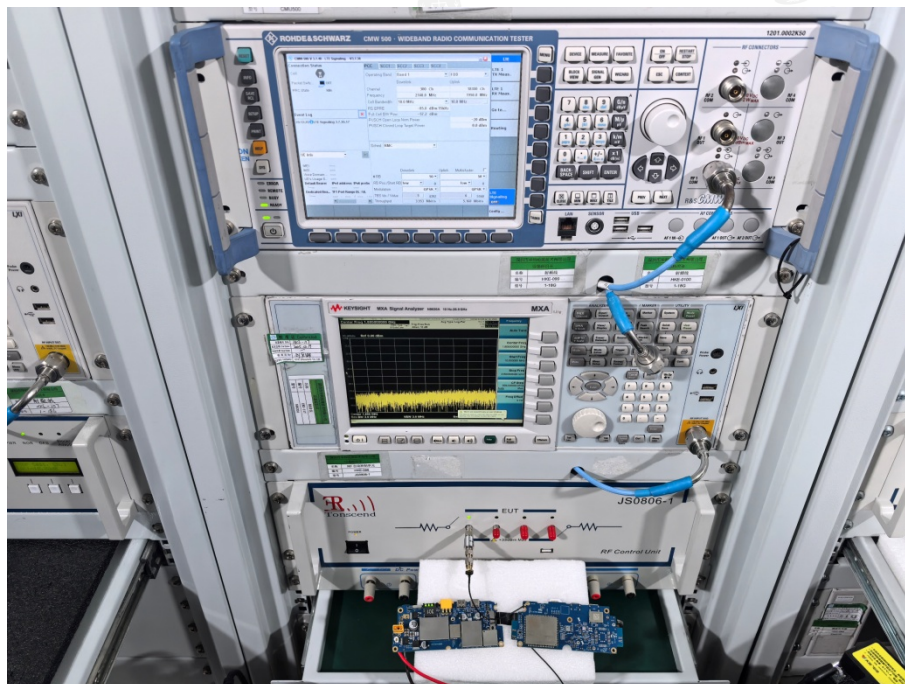
Radiated Emissions



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Shenzhen HUAKE Testing Technology Co., Ltd. Tel.: +86-0755-2302 9901 E-mail: info@huak.com Web.: www.huak.com
Add.: 1-2/F., Building B2, Junfeng Zhongcheng Zhizao Innovation Park, Heping, Fuhai Street, Bao'an District, Shenzhen, Guangdong, China

RF Conducted Emission





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5 Photos of the EUT

Reference to the report: ANNEX A of external photos and ANNEX B of internal photos.

.....**End of Report**.....

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Shenzhen HUAKE Testing Technology Co., Ltd. Tel.: +86-0755-2302 9901 E-mail: info@huak.com Web.: www.huak.com
Add.: 1-2/F., Building B2, Junfeng Zhongcheng Zhizao Innovation Park, Heping, Fuhai Street, Bao'an District, Shenzhen, Guangdong, China